# **ES3A THRU ES3M**

## SURFACE MOUNT SUPER FAST RECTIFIERS

Reverse Voltage - 50 to 1000 V

Forward Current - 3 A

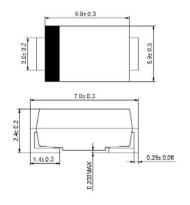
#### **Features**

- · High current capability
- · High surge current capability
- · High reliability
- Low reverse current
- · Low forward voltage drop
- · Super fast recovery time

### **Mechanical Data**

- Case: DO-214AB (SMC) molded plastic body
- · Epoxy: UL 94V-0 rate flame retardant
- · Lead: Lead formed for surface mount
- Mounting Position: Any

# DO-214AB(SMC)



Dimensions in millimeters

## **Maximum Ratings and Electrical Characteristics**

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half-wave, 60 Hz, resistive or inductive load, for capacitive load derate current by 20%.

Parameter	Symbols	ES3A	ES3B	ES3C	ES3D	ES3F	ES3G	ES3J	ES3K	ES3M	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	150	200	300	400	600	800	1000	V
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	105	140	210	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	150	200	300	400	600	800	1000	V
Maximum Average Forward Current	I <sub>F(AV)</sub>	3									Α
Peak Peak Forward Surge Current, 8.3 ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC Method)	I <sub>FSM</sub>	100									А
Maximum Forward Voltage at I <sub>F</sub> = 3 A	V <sub>F</sub>	0.95 1.3 1.7						V			
	I <sub>R</sub>	10 500								μА	
Maximum Reverse Recovery Time 1)	t <sub>rr</sub>	35									ns
Typical Junction Capacitance 2)	C <sub>J</sub>		50 40							pF	
Junction Temperature Range	Tj	- 55 to + 150								°C	
Storage temperature range	$T_{Stg}$	- 55 to + 150									°C

 $<sup>^{1)}</sup>$  Reverse recovery test conditions:  $I_F = 0.5 \text{ A}$ ,  $I_R = 1 \text{ A}$ ,  $I_{rr} = 0.25 \text{ A}$ 



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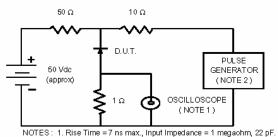


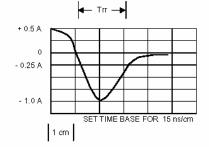


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<sup>&</sup>lt;sup>2)</sup> Measured at 1 MHz and applied reverse voltage of 4 V D.C.

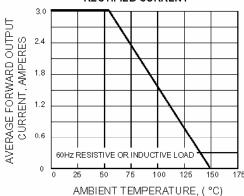
## FIG.1 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

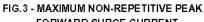


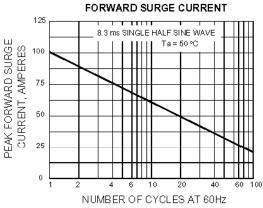


- - 2. Rise time = 10 ns max., Source Impedance = 50 ohms.
  - 3. All Resistors = Non-inductive Types.

FIG.2 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT







## FIG.4 - TYPICAL FORWARD CHARACTERISTICS

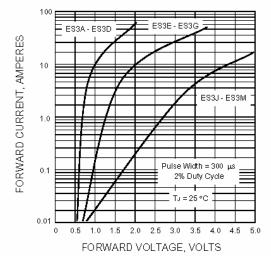
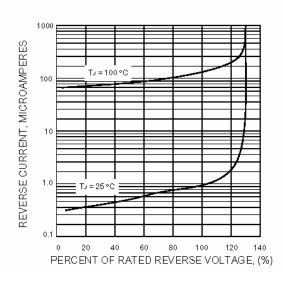


FIG.5 - TYPICAL REVERSE CHARACTERISTICS





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